



MMST2907A

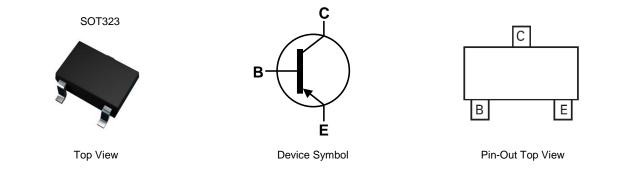
60V PNP SMALL SIGNAL TRANSISTOR IN SOT323

Features

- BV_{CEO} > -60V
- I_C = -600mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMST2222A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.006 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMST2907A-7-F	Active	AEC-Q101	K3F	7	8	3,000
MMST2907AQ-7	Active	Automotive	K3F	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

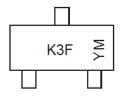
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally

the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/. 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K3F = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: A = 2013) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	0	2011	2	012	2013	2014	2015	201	6 20	17 2	2018	2019	2020
Code	Х		Y		Z	А	В	С	D	E		F	G	Н
Mont	h	Ja	in Fe	b	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2		3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	Ι _C	-600	mA

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

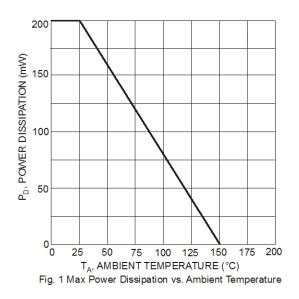
ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information





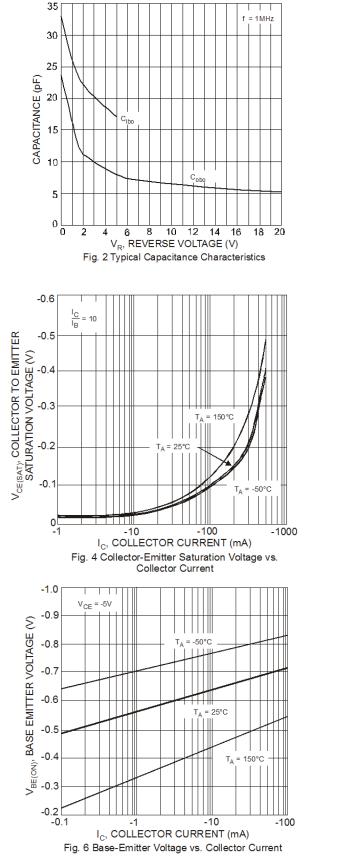
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

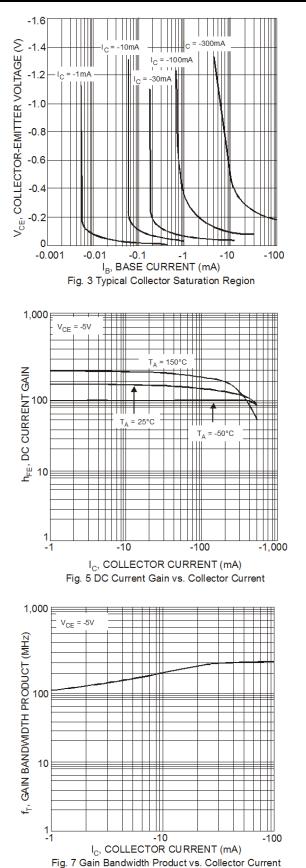
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	BV _{CBO}	-60	_	V	$I_{\rm C} = -10\mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-60	_	V	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-5		V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Base Cutoff Current	I _{СВО}	—	-10	nΑ μΑ	$V_{CB} = -50V, I_E = 0$ $V_{CB} = -50V, I_E = 0, T_A = +125^{\circ}C$
Collector Cutoff Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Base Cutoff Current	I _{BL}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
ON CHARACTERISTICS (Note 8)					· · ·
DC Current Gain	h _{FE}	75 100 100		_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} = -10V \\ I_{C} &= -1mA, \ V_{CE} = -10V \\ I_{C} &= -10mA, \ V_{CE} = -10V \end{split}$
		100 50	300 —		I _C = -150mA, V _{CE} = -10V I _C = -500mA, V _{CE} = -10V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.4 -1.6	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}		1.3 2.6	V	$I_{C} = -150mA$, $I_{B} = -15mA$ $I_{C} = -500mA$, $I_{B} = -50mA$
SMALL SIGNAL CHARACTERISTICS			•		
Output Capacitance	C _{OBO}	_	8	pF	$V_{CB} = -10V, f = 1.0MHz, I_E = 0$
Input Capacitance	CIBO		30	pF	$V_{EB} = -2V, f = 1.0MHz, I_{C} = 0$
Current Gain-Bandwidth Product	fT	200	—	MHz	$V_{CE} = -20V, I_C = -50mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					1
Turn-On Time	t _{ON}	_	45	ns	Vcc = -30V. lc = -150mA.
Delay Time	t _D	—	10	ns	$I_{B1} = -15mA$
Rise Time	t _R	—	40	ns	
Turn-Off Time	t _{OFF}	_	100	ns	$V_{CC} = -6V, I_{C} = -150mA,$
Storage Time	t _S	_	80	ns	$I_{B1} = I_{B2} = -15 \text{mA}$
Fall Time	t _F		30	ns	

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

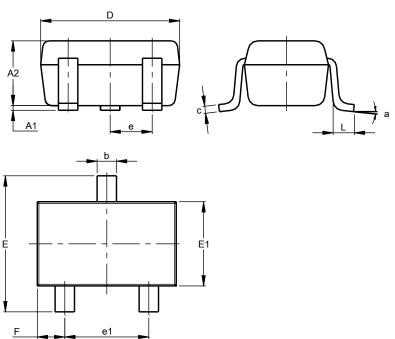






Package Outline Dimensions

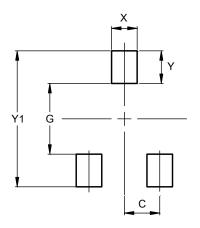
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
c	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 B	SC				
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°	_				
All	Dimen	sions i	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323

SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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